

IGBT

Trench & Field Stop IGBT
MWGC075N120H1

Data Sheet

Industrial Power Module & Discrete Transistor





Table of Contents

Title Page	
Applications and Features	3
Component Parameters	3
Maximum Ratings	4
Static Characteristics	4
Electrical Characteristics	4
More Electrical Characteristics Information	5
Chip Drawing (Size-mm ²)	6
Revision History	7
Relevant Application Notes	7
Attention	8
Legal Disclaimer	9
Service Information	10
Back Cover	





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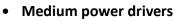
1200V / 75A Field-Stop IGBT

Features :

Recommended for :

- 1200V Trench & Field Stop technology Discrete components
- Low switching losses
- Easy paralleling
- Positive temperature coefficient

Applications :



- Uninterruptible power supplies
- Welding

Chip Type	V _{CE}	I _{Cn}	Die Size	Package
MWGC075N120H1	1200 V	75 A	9.315 x 6.52 mm ²	IGBT Wafer

Mechanical Parameters

Die size	9.315 x 6.52		
Emitter pad size	See chip drawing (Size-mm ²)	mm ²	
Gate pad size	0.803 X 1.301	mm	
Area total	60.7338		
Silicon thickness	130	μm	
Wafer size	150	mm	
Maximum possible chips per wafer	232 ea		
Scribe line	80 um		
Passivation frontside	w/o Polyimide		
Pad metal	5000nm AlSiCu		
Backside metal	Al Ti Ni Ag - system		
Reject ink dot size	Ø 0.65 mm ; Max. 0.762 mm		
Die bond	Electrically conductive epoxy glue and solder		
Wire bond	Al, ≤ 400μm		
Recommended storage environment	Store in original container , in dry nitrogen cabinet , in dark environment , in humidity below < 20% , < 6 months at an ambient temperature of $23^{\circ}C$.		







MWGC075N120H1

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage, T _j =25°C	V _{CE}	1200	V
DC collector current, limited by $T_{j max}^{1}$	Ι _C	-	А
Pulsed collector current, t_p limited by $T_{j max}^2$	I _{C,puls}	225	А
Gate-emitter voltage	V _{GE}	±30	V
Operating junction temperature	T _{vj}	-40~+150	°C
Short circuit data ² V_{GE} =15V, V_{CC} =600V, T_{vj} =25°C	t _{sc}	10	μs

Static Characteristics (tested on wafer) , $T_j=25^{\circ}C$

Parameter	Symbol	Conditions	Value			Unit
	Symbol	conditions	Min.	Тур.	Max.	Onit
Collector-emitter breakdown voltage	$V_{(BR)CES}$	<i>V</i> _{GE} =0V, <i>I</i> _C =1.0mA	1200	-	-	
Collector-emitter saturation voltage	$V_{CE(sat)}$	V _{GE} =15V, <i>I</i> _C =30A	1.15	1.60	2.25	V
Gate-emitter threshold voltage	$V_{\rm GE(th)}$	$I_{\rm C}$ =1.0mA, $V_{\rm GE}$ = $V_{\rm CE}$	5.3	6.0	6.7	
Zero gate voltage collector current	I _{CES}	V _{CE} =1200V, V _{GE} =0V	-	-	1	uA
Gate-emitter leakage current	I _{GES}	V _{CE} =0V, V _{GE} =30V	-	-	100	nA
Integrated gate resistor	r _G	-		1		Ω

Electrical Characteristics (not subject to production test - verified by design/characterization)

Parameter	Symbol Conditions		Value			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{CF} =25V,	-	7285	-	
Output capacitance	Coss	V _{GE} =0V, <i>f</i> =1MHz,	-	254	-	рF
Reverse transfer capacitance	C _{res}	7 _{vj} =25℃	-	25	-	

¹ Depending on thermal properties of assembly.

² Not subject to production test - verified by design/characterization.





More Electrical Characteristics Information

Dynamic Switching characteristics and thermal properties are depending on package design and mounting technology and can therefore not be specified for a bare wafer.

With Anti-Parallel Diode

Application example		Rev.
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Without Anti-Parallel Diode

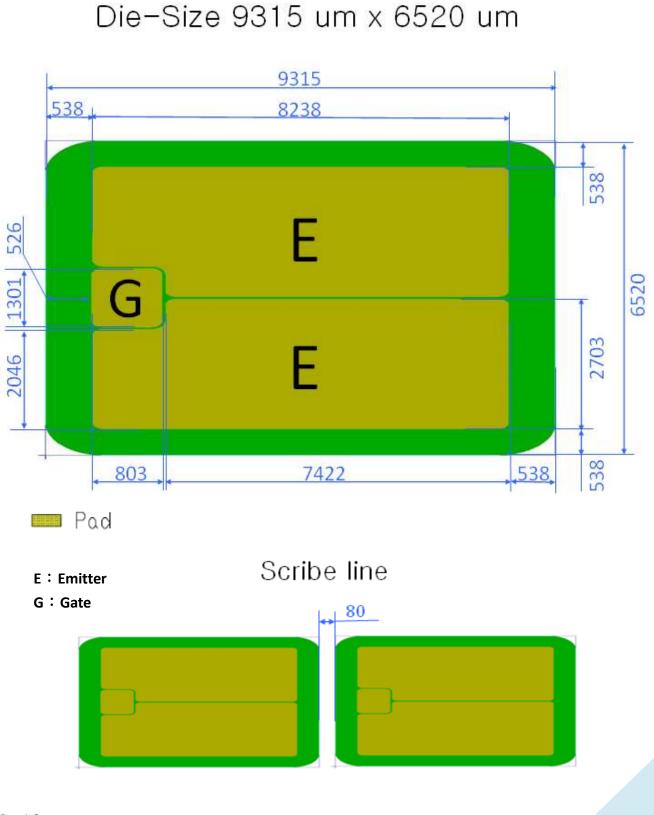
Application example		Rev.
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MWGC075N120H1

Chip Drawing (Size-mm)







MWGC075N120H1

IGBT Wafer Product Specifics

Dynamic test coverage at wafer level cannot cover all application conditions. Therefore it is recommended to test all characteristics which are relevant for the application at package level, including RBSOA, SCSOA and SSOA.

Revision History

Revision	Subjects (major changes since last revision)	Date
1.0	Final data sheet	May,2023

Relevant Application Notes Information

Revision	Summary	Date





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MWGC075N120H1

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